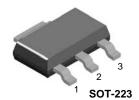


December 2009

FJT44 NPN Epitaxial Silicon Transistor

Features

· High Voltage Transistor



1. Base 2. Collector 3. Emitter

Absolute Maximum Ratings* T_A=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	500	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	e 6	
I _C	Collector Current	300	mA
P _C	Collector Dissipation (T _A = 25 °C)	2	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature Range	- 55 to +150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired. **NOTES:**

Thermal Characteristics* T_A=25°C unless otherwise noted

Symbol	Parameter	Value	Units	
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient	62.5	°C/W	

^{*} Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm. mounting pad for the collector lead min. 6 cm²

Ordering Information

Part Number	Package	Packing size	Packing Method	Remarks
FJT44KTF	SOT-223	2500 pcs	Tape and Reel	
FJT44TF	FJT44TF SOT-223		Tape and Reel	

¹⁾ These ratings are based on a maximum junction temperature of 150°C.

²⁾ These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics* T_A = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	500			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 1 \text{mA}, I_B = 0$	400			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 100 \mu A, I_C = 0$	6			V
I _{CBO}	Collector-Base Cutoff Current	V _{CB} = 400V, I _E = 0			100	nA
I _{CES}	Collector-Emitter Cutoff Current	V _{CE} = 400V, V _{BE} = 0			500	nA
I _{EBO}	Emitter-Base Cutoff Current	$V_{CE} = 4V, I_C = 0$			100	nA
h _{FE}	DC Current Gain	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$	40 50 45 40		200	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 1 \text{mA}, I_B = 0.1 \text{mA}$ $I_C = 10 \text{mA}, I_B = 1 \text{mA}$ $I_C = 50 \text{mA}, I_B = 5 \text{mA}$			0.4 0.5 0.75	V V
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_C = 10$ mA, $I_B = 1$ mA			0.75	V
C _{obo}	Output Capacitance	$V_{CB} = 20V, I_{E} = 0, f = 1MHz$			7	pF

^{*} Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2.0%

Typical Performance Characteristics

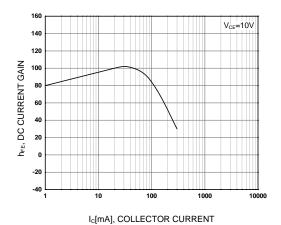


Figure 1. DC current Gain

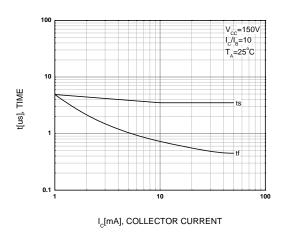


Figure 3. Turn-Off Switching Times

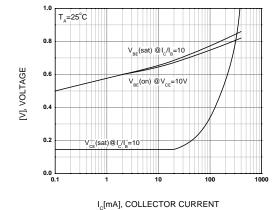


Figure 5. On Voltage

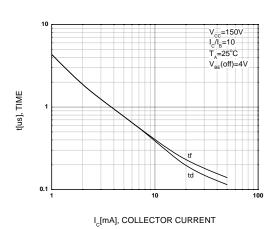


Figure 2. Turn-On Switching Times

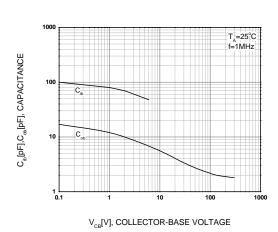


Figure 4. Capacitance

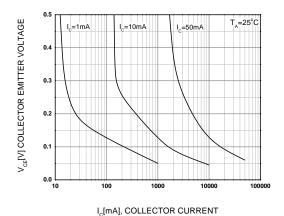


Figure 6. Collector Saturation Region

Typical Performance Characteristics (Continued)

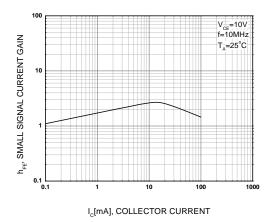
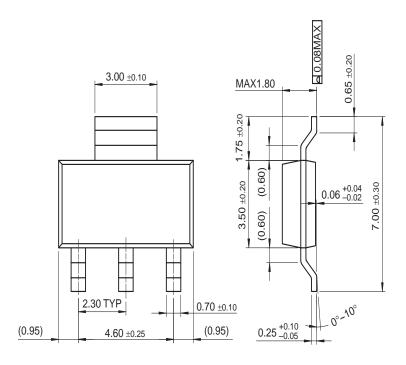
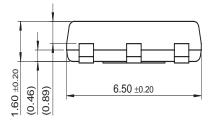


Figure 1. High Frequency Current Gain

Physical Dimensions

SOT-223





Dimensions in Millimeters





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Definition of Terms

Definition of Terms				
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Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
No Identification Needed Full Production		Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.		
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